"RESPONSE UNDER 37 CFR 1.116-EXPEDITED PROCEDURE EXAMINING GROUP 2814 "

Docket No.

214391US2S

IN RE APPLICATION OF:

Hidetaka HATTORI

SERIAL NO:

09/961,248

FILED:

September 25, 2001

FOR:

POWER SEMICONDUCTOR DEVICE AND MANUFACTURING METHOD THEREOF

	STANT COMMISSIONER FOR PATENTS SHINGTON, D.C. 20231	(C)	ren	
SIR:	Transmitted herewith is a Supplemental Amendment in the above-identified application.	() ()	등 2	
	No additional fee is required		r7	
	Small entity status of this application under 37 C.F.R. §1.9 and §1.27 is claimed.	L.1	100	

Additional documents filed herewith: With Marked-Up Copy, Petition for Extension of Time

The Fee has been calculated as shown below:

CLAIMS	CLAIMS REMAINING		HIGHEST NUMBER PREVIOUSLY PAID	NO. EXTRA CLAIMS		RATE		CALCULATIONS
TOTAL	40	MINUS	40	0	х	\$18	=	\$0.00
INDEPENDENT 4		MINUS	4	0	х	\$84	=	\$0.00
		☐ MULTIPI	E DEPENDENT (CLAIMS	+	\$280	=	\$0.00
			TOTAL OF	ABOVE CAI	LCU	LATIO	NS	\$0.00
		☐ Reduction by 50% for filing by Small Entity						\$0.00
	☐ Recordation of Assignment				\$40	=	\$0.00	
		TO					AL	\$0.00

- \triangle A check in the amount of \$110.00 is attached.
- Please charge any additional Fees for the papers being filed herewith and for which no check is enclosed herewith, or credit any overpayment to deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.
- ☑ If these papers are not considered timely filed by the Patent and Trademark Office, then a petition is hereby made under 37 C.F.R. §1.136, and any additional fees required under 37 C.F.R. §1.136 for any necessary extension of time may be charged to Deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.

OBLON, SPIVAK, McCLELLAND, MAIER & NEUSTADT, P.C.

22850

Customer Number 22850 Tel. (703) 413-3000 Fax. (703) 413-2220 (OSMMN 10/01)

(OSMMN 10/01) I:\ATTY\KMB\214391US\cvR2.doc Gregory J. Maier

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214391US-2S

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF

:

HIDETAKA HATTORI

: EXAMINER: FARAHANI, D.

SERIAL NO: 09/961,284

FILED: SEPTEMBER 25, 2001

: GROUP ART UNIT: 2814

FOR: POWER SEMICONDUCTOR

DEVICE AND MANUFACTURING

METHOD THEREOF

SUPPLEMENTAL AMENDMENT

SUPPLEMENTAL AMENDMENT

APRO 1 2003

ASSISTANT COMMISSIONER FOR PATENTS WASHINGTON, D.C. 20231

SIR:

This is a supplemental response to the amendment filed November 5, 2002. Having entered the amendment filed November 5, 2002, please further amend the above-identified application as follows:

FAX RECEIVED

APR 0 7 2003

IN THE CLAIMS

Please amend Claims 1, 11, 21, and 31 as shown in clean form below.1

GROUP 3600

- 1. (Four Times Amended) A power semiconductor device comprising:
- a base layer of a first conductivity type;
- a base layer of a second conductivity type selectively formed on one surface of said base layer of the first conductivity type;

¹A marked-up copy of the amended portion of the claims is attached hereto.